

GI42C

PNP EPITAXIAL PLANAR TRANSISTOR

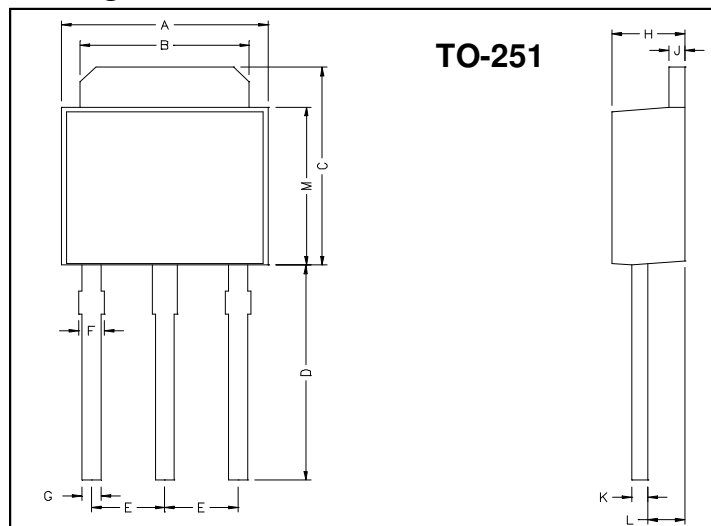
Description

The GI42C is designed for use in general purpose amplifier and switching applications.

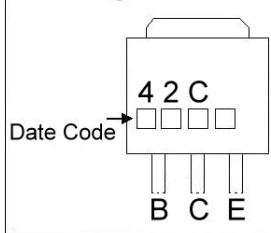
Features

*Complementary to GI41C

Package Dimensions



Marking :



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	6.40	6.80	G	0.50	0.70
B	5.20	5.50	H	2.20	2.40
C	6.80	7.20	J	0.45	0.55
D	7.20	7.80	K	0.45	0.60
E	2.30 REF.		L	0.90	1.50
F	0.60	0.90	M	5.40	5.80

Absolute Maximum Ratings (Ta = 25°C, unless otherwise specified)

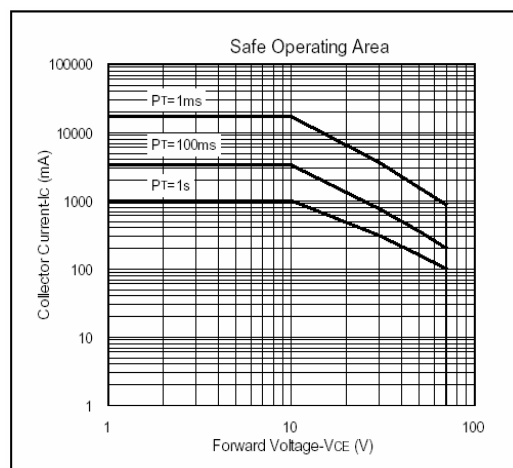
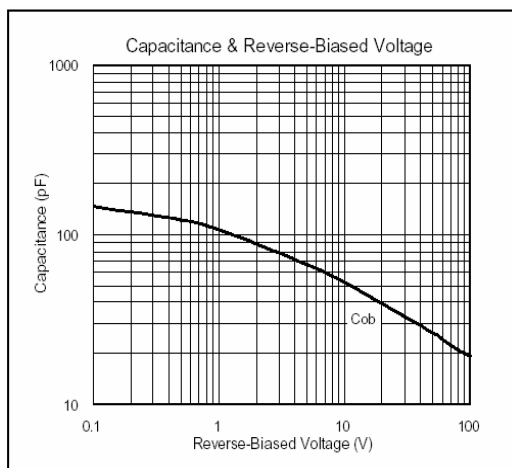
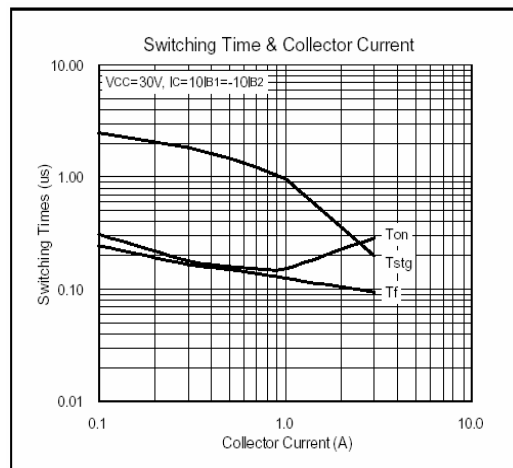
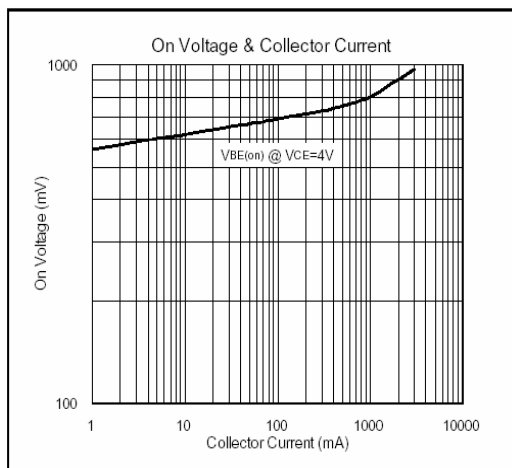
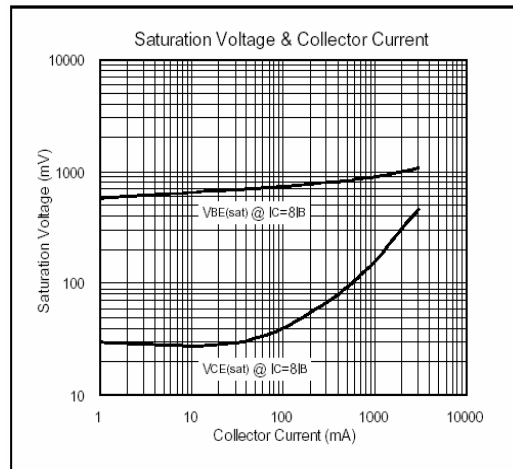
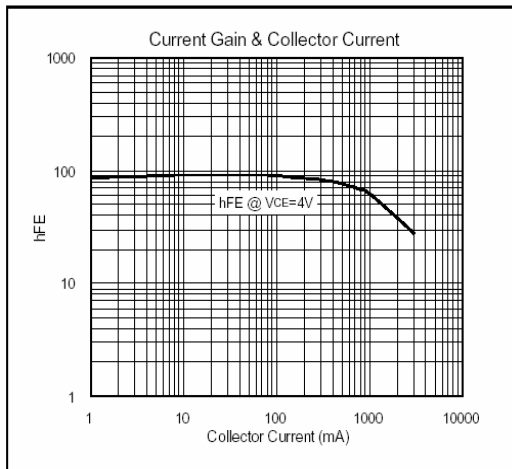
Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V _{CB0}	-100	V
Collector to Emitter Voltage	V _{CEO}	-100	V
Emitter to Base Voltage	V _{EB0}	-5	V
Collector Current (DC)	I _C	-6	A
Collector Current (Pulse)	I _C	-10	A
Junction Temperature	T _j	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C
Total Power Dissipation	P _D	2	W
	P _D (T _C =25°C)	20	W

Electrical Characteristics (Rating at Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CB0}	-100	-	-	V	I _C =-1mA, I _E =0
*BV _{CEO}	-100	-	-	V	I _C =-30mA, I _B =0
BV _{EB0}	-5	-	-	V	I _E =-100uA, I _C =0
I _{CES}	-	-	-10	uA	V _{CE} =-100V, V _{EB} =0V
I _{CEO}	-	-	-50	uA	V _{CE} =-60V, I _B =0
I _{EB0}	-	-	-500	uA	V _{EB} =-5V, I _C =0
*V _{CE(sat)}	-	-	-1.5	V	I _C =-6A, I _B =-600mA
*V _{BE(on)}	-	-	-2.0	V	V _{CE} =-4V, I _C =-6A
*h _{FE1}	30	-	-		V _{CE} =-4V, I _C =-300mA
*h _{FE2}	15	-	75		V _{CE} =-4V, I _C =-3A
f _T	3	-	-	MHz	V _{CE} =-10V, I _C =-500mA, f=1MHz

* Pulse Test: Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

Characteristics Curve



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